

L Number	Hits	Search Text	DB	Time stamp
1	0	(forming adj layers adj2 substrates) and (forming adj trenched adj isolation adj regions)	USPAT	2004/06/01 15:23
2	0	(forming adj trenched adj isolation) and catalyst and mixture and fluid and precursor and (supercritical adj fluid) and (insulative adj material) and temperature and threshold	USPAT	2004/06/01 15:26
3	0	(forming adj trench adj isolation) and catalyst and mixture and fluid and precursor and (supercritical adj fluid) and (insulative adj material) and temperature and threshold	USPAT	2004/06/01 15:26
4	0	(forming adj trench adj isolation) and catalyst and mixture and fluid and precursor and (supercritical adj fluid) and (insulative adj material) and temperature and threshold	USPAT	2004/06/01 15:26
5	0	(t trench adj isolation) and catalyst and mixture and fluid and precursor and (supercritical adj fluid) and (insulative adj material) and temperature and threshold	USPAT	2004/06/01 15:27
6	0	(t trench adj isolation) and catalyst and mixture and fluid and precursor and (insulative adj material) and temperature and threshold	USPAT	2004/06/01 15:27
7	0	(t trench adj isolation) and mixture and fluid and precursor and (insulative adj material) and temperature and threshold	USPAT	2004/06/01 15:28
9	0	(t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and (insulative adj material)	USPAT	2004/06/01 15:29
10	0	(t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and (insulation adj material)	USPAT	2004/06/01 15:30
11	0	(t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and insulative and insulation and insulating and electrically	USPAT	2004/06/01 15:31
12	0	(t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and insulative and insulating and electrically	USPAT	2004/06/01 15:31
13	16	(t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and insulating and electrically	USPAT	2004/06/01 15:31
14	1	(t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and insulating and electrically and (insulating adj material)	USPAT	2004/06/01 15:31
15	16	((t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold and chamber and insulating and electrically) and (region or trench or isolation or shallow or electrical or electrically or insulative or insulation or insulating or material or temperature or threshold or chamber or reaction or apparatus or initial or fluid or mixture or mixedure or heat or oxygen or silicon or oxide or dioxide or nitride)	USPAT	2004/06/01 15:59
8	20	((t trench adj isolation) and mixture and fluid and precursor and material and temperature and threshold	USPAT	2004/06/01 15:59
16	1	("6039834").PN.	USPAT	2004/06/01 15:59
17	1	((("6039834").PN.) and (region or trench or isolation or shallow or electrical or electrically or insulative or insulation or insulating or material or temperature or threshold or chamber or reaction or apparatus or initial or fluid or mixture or mixedure or heat or oxygen or silicon or oxide or dioxide or nitride))	USPAT	2004/06/01 16:01
18	1	("6645303").PN.	USPAT	2004/06/01 16:00
19	1	((("6645303").PN.) and (region or trench or isolation or shallow or electrical or electrically or insulative or insulation or insulating or material or temperature or threshold or chamber or reaction or apparatus or initial or fluid or mixture or mixedure or heat or oxygen or silicon or oxide or dioxide or nitride))	USPAT	2004/06/01 16:03

20		1	("6099647").PN.	USPAT	2004/06/01 16:03
21		1	((("6099647").PN.) and (region or trench or isolation or shallow or electrical or electrically or insulative or insulation or insulating material or temperature or threshold or chamber or reaction or apparatus or initial or fluid or mixture or mixed or heat or oxygen or silicon or oxide or dioxide or nitride)	USPAT	2004/06/01 16:14
22		1009	438/680	USPAT	2004/06/01 16:14
23		492	438/681	USPAT	2004/06/01 16:14
24		1282	438/700	USPAT	2004/06/01 16:14
25		704	438/770	USPAT	2004/06/01 16:15
26		45	438/772	USPAT	2004/06/01 16:15
27		242	438/773	USPAT	2004/06/01 16:15
28		324	438/905	USPAT	2004/06/01 16:15
29		152	438/954	USPAT	2004/06/01 16:15

6/1/04